



Light Emitting Diode

Features

- •Package (L/W/H) : 2.0 × 1.25 × 0.8 mm
- Color : Ultra Bright Green
- •Lens: Water Clear Flat Mold
- •EIA STD Package
- •Meet ROHS, Green Product
- Compatible With SMT Automatic Equipment
- •Compatible With Infrared Reflow Solder And Wave Solder Process



MAXIMUM RATINGS AND CHARACTERISTICS

@ 25°C Ambient Temperature (unless otherwise noted)

Parameter	Symbol	Rating	Unit		
Power Dissipation	Pd	100	mW		
Peak Forward Current (1/10 Duty Cycle, 0.1ms Pulse Width)	IFP	100	mA		
DC Forward Current	IF	30	mA		
Reverse Voltage	VR	5	v		
Operating Temperature Range	Topr	-30°C ~ +85°C			
Storage Temperature Range	Tstg	-40°C ~ +90°C			
Soldering Condition	Tsol	Reflow soldering : 260°C For 5 Seconds Hand soldering: 300°C For 3 Seconds			

Electrical Specification (TA=25°C unless otherwise specified)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Test Condition
Luminous Intensity	IV		320		mcd	IF = 20mA
Viewing Angle	201/2		120		deg	IF = 20mA
Dominant Wavelength	λd		520		nm	IF=20mA
Peak Wavelength	λp		525		nm	IF=20mA
Spectral Line Half-Width	Δλ		15		nm	IF=20mA
Forward Voltage	VF	2.9		3.4	V	IF=20mA
Reverse Current	IR			10	uA	VR=5V

Notes: 1. Luminous intensity is measured with a light sensor and filter combination that approximates the CIE eye-response curve.

 $2.\,\theta 1/2$ is the off-axis angle at which the luminous intensity is half the axial luminous intensity.

3. The dominant wavelength, λd is derived from the CIE chromaticity diagram and represents the

single wavelength which defines the color of the device.



RATINGS AND CHARACTERISTIC CURVES



Fig.5 Luminous Intensity vs.Ambient Temperature



80°